VOLUME 60, NUMBER 4

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(Received 17 March 1999)

Magnetic semiconductors offer a unique possibility for strongly tuning the intrinsic alloy disorder potential with applied magnetic field. We report the direct observation of a series of steplike reductions in the magnetic alloy disorder potential in single ZnSe/Zn(Cd, Mn)Se quantum wells between 0 and 60 T. This disorder, measured through the linewidth of low-temperature photoluminescence spectra, drops abruptly at ~19, 36, and 53 T, in concert with observed magnetization steps. Conventional models of alloy disorder (developed for nonmagnetic semiconductors) reproduce the general shape of the data, but markedly underestimate the size of the linewidth reduction. [S0163-1829(99)50328-7]

By their very nature, all semiconductor alloys possess some degree of compositional disorder. The magnitude and character of this intrinsic disorder are of keen interest to researchers and growers of alloyed semiconductors, who often rely on photoluminescence (PL) spectroscopy to infer material quality. Even in nominally "clean" alloys, the intrinsic compositional disorder leads to spatially varying exciton energies and inhomogeneously broadened PL linewidths. Theoretical models^{1,2} have been proposed to account for the observed PL linewidths in nonmagnetic alloys such as $Al_{1-x}Ga_xAs$ and $In_{1-x}Ga_xP$, where, for a given sample, the alloy fluctuation potential is fixed. However, a more rigorous test of these models would involve a material system in which the intrinsic disorder potential itself is tunable.

In contrast with nonmagnetic semiconductors, magnetic semiconductor alloys (e.g., $Zn_{1-x-y}Cd_xMn_ySe$) offer the unique possibility for tuning the magnetic disorder potential in a single sample through the application of magnetic field. The local conduction and valence-band edges near a magnetic Mn²⁺ cation are closely tied to its spin orientation through the strong J_{sp-d} exchange interaction between the band electrons and holes and the localized d electrons that comprise the $S = \frac{5}{2} \text{ Mn}^{2+}$ spin.³ In a magnetic field, the local band gap near a Mn²⁺ moment changes by $\frac{1}{2}(\alpha - \beta)\langle S_z \rangle$, where $\langle S_z \rangle$ is the expectation value of the Mn²⁺ spin and $(\alpha - \beta)$ is the J_{sp-d} exchange integral, usually of order 1 eV.^{3,4} At low temperatures, even modest fields (H < 1 T) can dramatically shift—by hundreds of meV—the effective band gap near the Mn^{2+} cations, directly changing the alloy disorder potential seen by a microscopic probe (such as an exciton) and serving as a clear and direct test of present theoretical models.

In this paper, we show direct evidence for a field-induced

annealing of the magnetic fluctuation potential in single ZnSe/Zn(Cd, Mn)Se magnetic quantum wells. A rapid reduction in the magnetic disorder, measured as a drop in PL linewidth, occurs at low fields (H < 5 T) as the isolated (paramagnetic) Mn²⁺ spins align, and then in stepwise fashion at high magnetic fields when antiferromagnetically bound pairs of Mn²⁺ cations unlock. The magnitude of this stepwise linewidth annealing is over six times larger than predicted by present theories of disorder broadening in non-magnetic semiconductor alloys, suggesting that revisions are required to include magnetic alloy disorder.

These high-field PL measurements are enabled by the 60-T Long-Pulse magnet at the National High Magnetic Field Laboratory (Los Alamos). Powered by a 1.4GVA motor generator, the 2-s pulse duration of this magnet represents a hundredfold increase in time "at field" as compared with traditional capacitor-driven pulsed magnets. Using highspeed charge coupled device cameras,⁵ up to 2000 highresolution (14-bit) optical spectra are acquired in a single 60-T magnet shot, permitting timely reconstruction of the entire field dependence and clear resolution of small amplitude, wavelength, and linewidth shifts as a function of magnetic field. Light is coupled to and from the samples via single optical fibers, and temperatures down to 350 mK are obtained with a fiberglass ³He refrigerator. The field profile from the Long-Pulse magnet is shown in Fig. 1(a), where the field variation between spectra is at most $\sim 165 \text{ mT}$ [inset, Fig. 1(a)]. The high light collection efficiency, low noise detector, and long pulse duration yields excellent signal-tonoise (>500) even with ms exposures and low laser excitation (<200 μ W at 400 nm in all cases).

The samples are molecular beam epitaxy grown, 120-Å wide $ZnSe/Zn_{0.80}Cd_{0.20}Se$ single quantum wells into which

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FIG. 1. (a) The field profile of the 60-T Long-Pulse magnet (and a capacitor-driven magnet for comparison). Inset: Expanded view; optical spectra are acquired at each point. (b) The Zeeman shift (\propto magnetization) of the PL peak from the $12 \times \frac{1}{4}$ ML MnSe quantum well, showing a Brillouin-like saturation followed by steps.

the magnetic species $(Mn^{2+}, S=\frac{5}{2})$ is "digitally" incorporated in the form of equally spaced fractional-monolayer planes of MnSe.⁶ We focus on samples containing 12 quarter-monolayer planes of MnSe $(12 \times \frac{1}{4} \text{ ML})$ and 24 eighth-monolayer planes of MnSe $(24 \times \frac{1}{8} \text{ ML})$. The wells are 39 monolayers wide, and since x-ray diffraction studies on "digital" superlattice samples reveal ~ 1 monolayer diffusion of Mn during growth, these structures have a nearly bulklike 8% Mn concentration. To verify this, a 120-Å quantum well containing the quaternary magnetic alloy Zn_{0.70}Cd_{0.22}Mn_{0.08}Se was also grown, and was found to exhibit nearly identical PL properties (intensity and Zeeman shift), albeit with a slightly larger linewidth (8.5 meV vs 6.8 meV for the digital samples, at zero field). With applied field, the PL spectra become σ^+ circularly polarized and show a large (\sim 50 meV) Zeeman redshift, corresponding to recombination of low energy electrons $(s_{z} = -\frac{1}{2})$ and holes $(j_z = -\frac{3}{2})$.³ The dominant J_{sp-d} exchange interaction generates this large exciton spin splitting, and as such, the Zeeman shift of the PL peak reliably tracks (and is a measure of) the magnetization of the Mn²⁺ ensemble in the quantum well.⁴

Figure 1(b) shows the measured Zeeman shift (\propto magnetization) from the $12 \times \frac{1}{4}$ ML quantum well to 60 T. At low fields, the magnetization rises rapidly and saturates by ~8 T. At higher fields, three magnetization steps are observed, corresponding to the partial unlocking of Mn-Mn nearestneighbor pairs. As with all diluted magnetic semiconductors, the Mn²⁺ spins in these samples interact with one another predominantly via an antiferromagnetic J_{NN} exchange, which binds up neighboring Mn²⁺ moments in spin clusters of varying size.⁷ Mn²⁺ singles, pairs, triples, and higher-order clusters occur with readily calculable probability assuming a well-defined (usually random) distribution of the Mn²⁺ moments.⁸ Isolated Mn²⁺ moments (singles) behave as $S = \frac{5}{2}$ paramagnets with a Brillouin-like susceptibility. Nearest-neighbor pairs of Mn²⁺ spins bind to form a cluster



FIG. 2. (a) Magnetization steps in the $12 \times \frac{1}{4}$ ML sample. (b) PL linewidth (Γ) from the $12 \times \frac{1}{4}$ ML, $24 \times \frac{1}{8}$ ML, and quaternary $Zn_{1-x-y}Cd_xMn_ySe$ quantum wells (bottom to top). Drops in Γ correlate with the magnetization steps. The steady, superimposed broadening arises from the shrinking exciton.

with total spin $S_T = 0$ at low fields. At low temperatures, when the applied field (H) is commensurate with the exchange energy $(H_n = 2nJ_{NN}/g_{Mn}\mu_B, n = 1, 2, ..., 5)$, the Mn-Mn pair "unlocks" and assumes total spin S_T =1,2,...,5, contributing a step in the magnetization. These magnetization steps are a well-studied signature of Mn-Mn pairs, from which can be determined the magnitude and nature of J_{NN} , as well as whether or not the Mn^{2+} spins are randomly distributed.⁹ Larger spin clusters (triples, quadruples, etc.) have increasingly complex susceptibilities that are usually modeled empirically.¹⁰ The data in Fig. 1(b) is characteristic of all our samples—both the $24 \times \frac{1}{8}$ ML digital sample and the quaternary Zn_{0.70}Cd_{0.22}Mn_{0.08}Se quantum well elicit similar Zeeman shifts to within 5%, in support of the assertion that the distribution of Mn²⁺ in all the samples is nearly bulklike. The magnetization steps at 18.8, 36.0, and 53.3 T (+-0.3 T) are shown on an expanded scale in Fig. 2(a). In practice, the fields H_n are not exact integer multiples due to distant-neighbor exchange fields between Mn mo-ments that contribute a net offset.¹¹ However, the difference $H_{n+1}-H_n$ is expected to reflect the exchange energy, and we determine $J_{NN} = -11.1$ K in these quaternary quantum wells.

Figure 2(b) shows the measured full width at half maximum linewidth (Γ) of the PL spectra, obtained through a Gaussian line shape fit to the data. $\Gamma(H)$ is characterized by a steady broadening, superimposed on which are a series of steplike reductions at low fields (H < 5 T), and at the Mn-Mn unlocking fields H_n . These data are interpreted as a series of field-driven reductions (i.e., annealings) of the large local band-gap energy E_{MnSe} (=3.4 eV) at magnetic Mn²⁺ sites. The slow (background) monotonic broadening of Γ is well understood from previous work on nonmagnetic semiconductors and is due *only* to the field-induced shrinking of the exciton size.^{1,2,12} We concentrate on the steplike reductions in Γ in the following. At low fields (H < 8 T), the en-



FIG. 3. The normalized linewidth (the broadening due to the shrinking exciton has been subtracted). At the magnetization steps, relative drops of 12%, 10%, and 4% are observed. The dotted line is the calculated $\Gamma(H)$ based on existing theories.

semble of isolated $S = \frac{5}{2}$ Mn²⁺ spins in the quantum well evolves from a random orientation [with mean $\langle S_z \rangle = 0$ and variance $\langle (S_z - \langle S_z \rangle)^2 \rangle = \frac{35}{12}$ to complete saturation ($\langle S_z \rangle =$ $-\frac{5}{2}$, variance=0), reducing the local band gap (and bandgap fluctuations) at Mn^{2+} sites and therefore reducing Γ (by 20% - 25%) in all magnetic samples. At the unlocking fields H_n , the Mn-Mn pairs ratchet into alignment with the applied field, lowering the local band gap and thereby contributing an additional smoothing to the magnetic disorder potential seen by the exciton. The size of these stepwise annealings is most clearly shown in Fig. 3, where the monotonic rise of Γ due to the shrinking exciton has been subtracted off, and the data normalized. The stepwise disorder annealing is now plainly evident (a nonmagnetic control sample was also studied, and showed only the monotonic increase in Γ with field). To our knowledge, these data are the first to observe incremental annealings of the disorder potential in alloyed semiconductors.

As shown in Fig. 3, the drops in Γ represent a 22%, 12%, 10%, and 4% relative decrease. These large changes in Γ are surprising since a random, 8% Mn²⁺ distribution would imply only $\sim 3\%$ of all cations sites are single Mn moments, and that less than 2% are Mn-Mn pairs. Indeed, extensions of existing models of disorder broadening do not account for the magnitude of the observed changes in Γ . In particular, the theories^{1,2} of Schubert, Mena, Lee and Bajaj, and of Lyo (which share a common model for alloy disorder), do accurately describe the field- and concentration-dependent PL linewidths in nonmagnetic $Al_xGa_{1-x}As$ and $In_xGa_{1-x}P$, but do not reproduce the data from the magnetic alloys presented in this paper. While the general shape of the calculated $\Gamma(H)$ is found to be quite reasonable, the magnitude of the observed linewidth steps are over six times larger than an adaptation of the above models predicts, as will be shown below. The following assumptions are common to all models of compositional disorder in alloyed semiconductors cited in Ref. 1: (i) The constituents are randomly distributed; (ii) Each cation site is assigned a local band gap equal to the band gap of its parent compound (e.g., ZnSe or MnSe); and (iii) Γ reflects the root-mean-square (rms) deviation of the

average band gap within an exciton's wave function (or "volume"). We construct a similar model that also includes the field-dependent local band gap of the Mn²⁺ cations that derives from the strong J_{sp-d} exchange. We consider the samples to be Zn_{0.70}Cd_{0.22}Mn_{0.08}Se alloys, comprised of cations of Zn, Cd, isolated Mn²⁺ spins, paired Mn²⁺ spins, and Mn²⁺ spins locked in larger clusters (triples, quadruples, etc.). These cations occur with concentration P_1 , P_2 , P_3 , P_4 , and P_5 , respectively, and have local band gaps Δ_1 $=E_{ZnSe}=2.82 \text{ eV}, \ \Delta_2=E_{CdSe}=1.87 \text{ eV}, \ \text{and} \ \Delta_3=\Delta_4=\Delta_5$ $=E_{MnSe} + \frac{1}{2}(\alpha - \beta)\langle S_z \rangle$. Here, $E_{MnSe} = 3.4 \text{ eV}$, $\langle S_z \rangle$ is the expectation value of the Mn²⁺ spin, and the exchange integral $(\alpha - \beta) = 1.37 \text{ eV}$ is the magnitude of the J_{sp-d} exchange interaction between the Mn²⁺ cation and the conduction and valence bands, chosen to be that from $Zn_{1-r}Mn_rSe.^3$ The probabilities of single, paired, and higher order Mn^{2+} clusters (P_3 , P_4 , and P_5) equal 3.0%, 1.7%, and 3.3%, respectively (assuming a random 8% Mn²⁺ distribution).

Following standard treatments of diluted magnetic semiconductors systems,^{3,4} isolated Mn²⁺ spins obey a modified Brillouin function, $\langle S_z \rangle = -\frac{5}{2} B_{5/2} (5 \mu_B g_{Mn} H/2k_B T^*)$, where $T^* = 3.5 \text{ K}$ is an empirical "effective temperature" that best fits the low-field susceptibility. For the Mn²⁺ spins in pairs, $\langle S_z \rangle = -\frac{1}{2}S_T$, where $S_T = \Sigma [1 + \exp(g_{\mathrm{Mn}} \mu_B(H_n))]$ $(-H)/k_BT$]⁻¹=0,1,...,5 is the total spin of the pair. For spins in higher-order clusters, we consider $\langle S_z \rangle = -\frac{1}{2}$ at high fields (>8 T), a reasonable approximation for triples and in accord with standard treatments for larger clusters.⁷ As our interest is in calculating the *relative* (rather than absolute) changes Γ that occur when Mn²⁺ spins align, we do not attempt a detailed description of the size and shape of the exciton wave function, which ultimately enters into Γ as a prefactor. As follows, the heart of the model-calculation of the rms fluctuation of the energy gap—is extended to the case of an arbitrary number of cation species. Previous expressions of Γ (Ref. 1) are recovered in the case of only two cation species.

Given an exciton energy $E = N^{-1} \Sigma E_j$ (j=1,...,N); the mean band gap of the *N* lattice sites within the exciton wave function), and an ensemble average $\mu = \langle E \rangle = \Sigma P_i \Delta_i$ (equal to PL line center), we compute the variance

$$\sigma^2 = \langle (E-\mu)^2 \rangle = N^{-1} \left(\left(\sum P_i \Delta_i^2 \right) - \mu^2 \right), \qquad (1)$$

where $\Gamma = 2\sqrt{2 \ln 2\sigma}$. As written, however, Eq. (1) does not implicitly account for the Boltzmann distribution of the isolated Mn²⁺ spins, which present an additional fluctuation that must be calculated separately, namely,

$$P_{3}\Delta_{3}^{2} \equiv P_{3}\sum Z^{-1}e^{-g_{\mathrm{Mn}}\mu_{B}HS_{z}/k_{B}T^{*}}(E_{\mathrm{MnSe}} + \frac{1}{2}(\alpha - \beta)S_{z})^{2},$$
(2)

where Z is the Mn²⁺ partition function and the sum is over the spin multiplet $S_z = -\frac{5}{2}, -\frac{3}{2}, ..., +\frac{5}{2}$. This additional fluctuation affects only the initial drop in Γ (H < 8 T), before the isolated Mn²⁺ spins saturate. The individual spins within Mn-Mn pairs are not treated similarly, due to their correlated nature; unlike isolated spins, fluctuations of the individual Mn²⁺ spins within a pair do *not* affect the exciton energy *E*,



FIG. 4. (a) The calculated $\Gamma(H)$, based on existing models of alloy disorder (solid line). Dashed (dotted) line shows calculated results for different values of the J_{sp-d} exchange (Mn concentration). Inset: The model to 100 T, predicting steplike increases in Γ at higher fields.

because the total spin S_T is fixed. Equations (1) and (2) yield $\Gamma = 8.22 \text{ meV}$ (assuming a spherical exciton wave function of radius 60 Å).

The dotted line in Fig. 3 shows the calculated $\Gamma(H)$, where it is clear that the model considerably underestimates the magnitude of the observed changes in Γ . The calculated initial drop in Γ (from the isolated Mn²⁺ spins) is only half as large as observed, and the drop at H_1 and H_2 (shown expanded in Fig. 4) is of order 2% and 1%, more than six times smaller than observed. On the other hand, the model does admirably reproduce the general shape of the data (Fig. 4), showing the comparatively large initial decrease, stepwise drops at H_n that decrease in size, and even the shallow local minimum observed at ~ 4 T in the digital samples. The model is quite robust against reasonable ($\sim 10\%$) uncertainty in the band gaps Δ_i , the concentrations P_i , and the exchange integral $(\alpha - \beta)$; for comparison, Fig. 4 also shows the calculated results assuming a 25% larger Mn concentration (dotted line), and a 20% decrease in $(\alpha - \beta)$ (dashed line), with little change. Even with grossly inaccurate input parameters, such as the assumption of all isolated, or all paired Mn spins, the model underestimates the size of the initial drop in Γ , or the relative drop at magnetization steps (not shown). Of interest, the model predicts stepwise increases in Γ at the fourth and fifth steps, at ~71 T and ~88 T (inset). Midway through the third magnetization step [for $(\alpha - \beta) = 1.37 \text{ eV}$], the local band gap of the Mn-Mn pairs drops below the mean band gap (μ), thus increasing the fluctuation potential once again. We anticipate that experiments in higher magnetic fields (or in samples with smaller J_{NN} , e.g., Cd_{1-x}Mn_xTe) will exhibit this behavior.

While the qualitative field dependence of Γ is well reproduced by our model, the magnitude of the stepwise reductions remains puzzling, suggesting that at least one of the underlying assumptions of the model is in error. For example, the assignment of a local, J_{sp-d} exchange-driven band gap to each Mn²⁺ cation site may be insufficient. While this approach works well as a starting point for mean-field treatments of general magneto-optical properties in dilute magnetic semiconductors,^{3,4} it may be inadequate for the computation of disorder. More likely, the large alloy fluctuations presented by the Mn²⁺ may act as electron and hole pinning centers, thus causing significant delocalization of the excitons when the magnetic alloy disorder is annealed at low fields and at the magnetization steps. Delocalization of the exciton wave function leads directly to an additional reduction in Γ [see Eq. (1)]. For example, a 23%, 20%, and 8% relative increase in exciton "volume" at H_1 , H_2 , and H_3 would lead to an additional 10%, 9%, and 4% relative drop in Γ , thereby reproducing the data very well. However, an accurate calculation of exciton delocalization based on a reduction in alloy disorder must await a more detailed theoretical treatment.

In summary, the long duration of the 60-T Long-Pulse magnet permits direct observation of an incremental annealing of the magnetic disorder potential at magnetization steps in ZnSe/Zn(Cd, Mn)Se single quantum wells through the linewidth of PL spectra. While Mn-Mn pairs comprise less than 2% of all cations, the relative decrease in Γ at the magnetization steps is as large as 12%. A model of the magnetic alloy disorder, based on models for nonmagnetic III-V systems, reproduces the general shape of the data but underestimates the size of the steps in Γ , suggesting that a new theory is required to properly account for magnetic disorder in alloyed semiconductors.

We gratefully acknowledge the technical assistance of M. Pacheco and W. Bowman, and support from Grants Nos. NSF DMR 97-01072 and 97-01484, and U.S. DOE Contract No. DE-AC04-94AL85000.

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